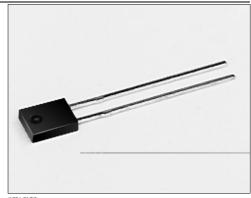
### Silicon Photodiode

### **FEATURES**

- Side-looking plastic package
- Linear response
- · Fast response time
- · Internal visible light rejection filter
- 50° (nominal) acceptance angle
- Mechanically and spectrally matched to SEP8506 and SEP8706 infrared emitting diodes



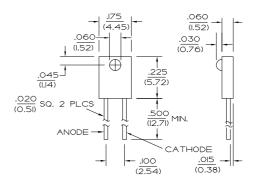
INFRA-79.TIF

### DESCRIPTION

The SDP8276 is a PN silicon photodiode, transfer molded in a side- looking black plastic package, to minimize the effects of visible ambient light. The chip is positioned to accept radiant energy through a lens on the side of the package. The SDP8276 photodiode offers fast response time and a linear output. It is ideal for battery powered systems or anywhere power is at a premium.

### **OUTLINE DIMENSIONS** in inches (mm)

 $\begin{array}{ccc} \text{Tolerance} & 3 \text{ plc decimals} & \pm 0.005 (0.12) \\ & 2 \text{ plc decimals} & \pm 0.020 (0.51) \end{array}$ 



DIM\_074.cdr

### Silicon Photodiode

### ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Light Current	l <sub>L</sub>	4	7		μΑ	V <sub>R</sub> =20 V
						H=1 mW/cm <sup>2 (1)</sup>
Dark Current	ΙD			50	nA	H=0, V <sub>R</sub> =20 VDC
Reverse Breakdown Voltage	$V_{BR}$	50			V	I <sub>R</sub> =10 μA, H=0
Angular Response (2)	Ø		50		degr.	I <sub>F</sub> =Constant
Rise And Fall Time	t <sub>r</sub> , t <sub>f</sub>		50		ns	$V_R=20 \text{ V}, R_L=50 \Omega$

- Notes

  1. The radiation source is an IRED with a peak wavelength of 935 nm.

  2. Angular response is defined as the total included angle between the half sensitivity points.

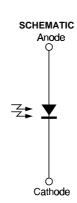
### **ABSOLUTE MAXIMUM RATINGS**

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -40 to +85°C -40 to +85°C Storage Temperature Range Soldering Temperature (5 sec) 240°C Cathode Anode Voltage 50 V Power Dissipation 100 mW (1)

### Notes

1. Derate linearly from 25°C free-air temperature at the rate of 0.78 mW/°C.



Honeywell reserves the right to make changes in order to improve design and supply the best products possible. Honeywell

### Silicon Photodiode

### SWITCHING TIME TEST CIRCUIT

Q + GaAs Emitter Anode 10 μS

SWITCHING WAVEFORM

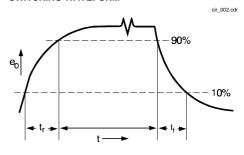


Fig. 1 Responsivity vs Angular Displacement 1.0 0.9

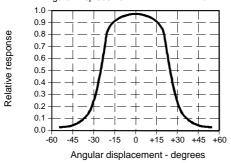


Fig. 2 Dark Current vs

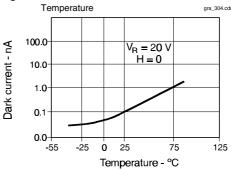
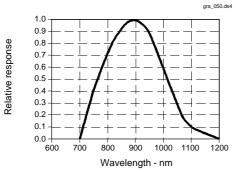


Fig. 3 Spectral Responsivity



All Performance Curves Show Typical Values



Silicon Photodiode





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